HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHED LASER

High energy diode pumped all solid state Q-switched laser at 1064nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in laser ranging, LIBS, LIF, ICP-MS, LCD repair, scientific research, and so on.









SPECIFICATIONS

Wavelength (nm)	1064±1
Operating mode	Q-switched: EOM (Electro-optic modulation)
Single pulse energy (mJ)	40
Pulse duration (ns)	~10
Rep. rate (Hz)	1~20, EXT (adjustable)
Energy stability (rms)	<2%, <3%, <5%
Beam divergence, full angle (mrad)	<3
Beam diameter (mm)	~4
Warm-up time (minutes)	<15
Beam height from base plate (mm)	53
Cooled method	Air cooled
Operating temperature (°C)	-30~60
Power supply (220V AC/24V DC)	PSU-DPS-J
Expected lifetime (pulses)	109
Warranty period	1 year
Available Options	Higher single pulse energy: up to 80mJ





